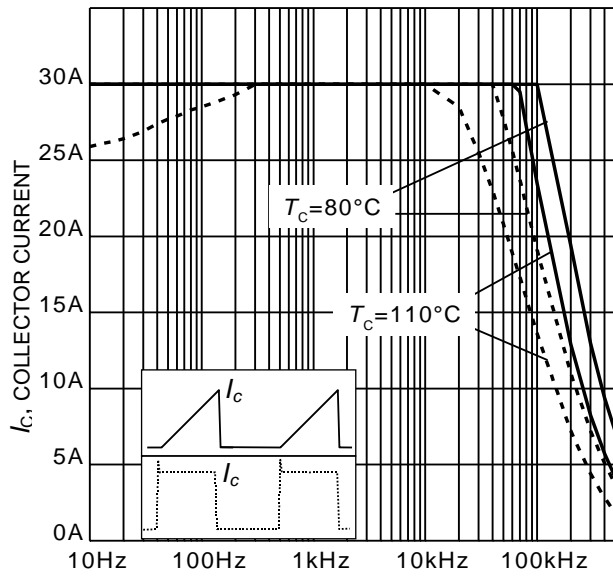


Rise time	t_r	$V_{CC}=400V, I_C=10A,$ $V_{GE}=0/15V, r_G=23\Omega,$ $L_\sigma=60nH, C_\sigma=40pF$	-	8	-	mJ
Turn-off delay time	$t_{d(off)}$		-	215	-	
Fall time	t_f		-	38	-	
Turn-on energy	E_{on}	L_σ, C_σ from Fig. E Energy losses include "tail" and diode reverse recovery.	-	0.16	-	
Turn-off energy	E_{off}		-	0.27	-	
Total switching energy	E_{ts}		-	0.43	-	

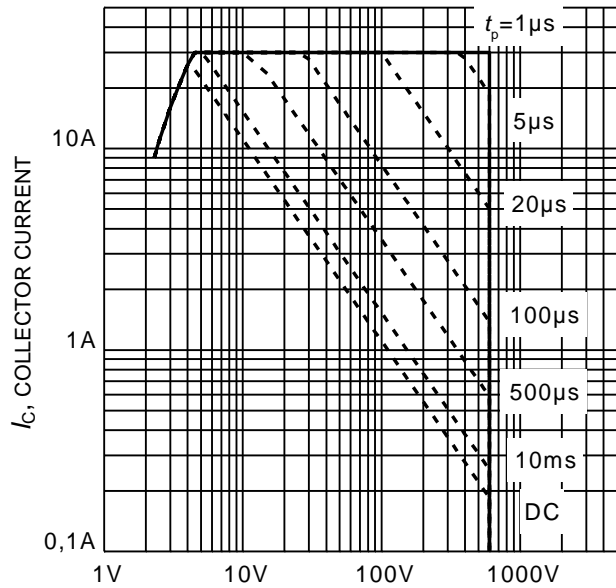
Switching Characteristic, Inductive Load, at $T_j=175^\circ C$

Parameter	Symbol	Conditions	Value			Unit
			min.	typ.	max.	
IGBT Characteristic						
Turn-on delay time	$t_{d(on)}$	$T_j=175^\circ C,$ $V_{CC}=400V, I_C=10A,$ $V_{GE}=0/15V, r_G=23\Omega,$ $L_\sigma=60nH, C_\sigma=40pF$ L_σ, C_σ from Fig. E Energy losses include "tail" and diode reverse recovery.	-	10	-	ns
Rise time	t_r		-	11	-	
Turn-off delay time	$t_{d(off)}$		-	233	-	
Fall time	t_f		-	63	-	mJ
Turn-on energy	E_{on}		-	0.26	-	
Turn-off energy	E_{off}		-	0.35	-	
Total switching energy	E_{ts}	-	0.61	-		



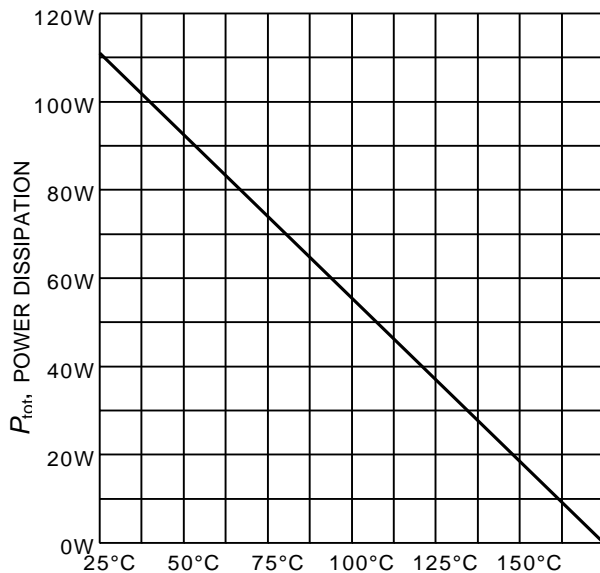
f_i , SWITCHING FREQUENCY

Figure 1. Collector current as a function of switching frequency
 ($T_j \leq 175^\circ\text{C}$, $D = 0.5$, $V_{CE} = 400\text{V}$,
 $V_{GE} = 0/15\text{V}$, $r_G = 23\Omega$)



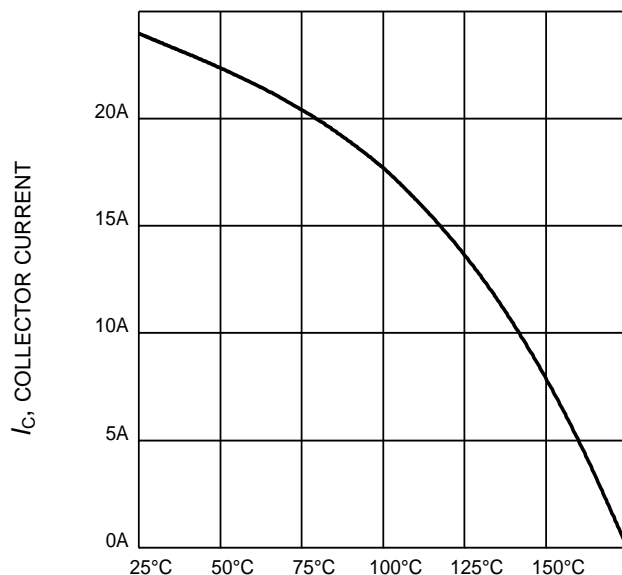
V_{CE} , COLLECTOR-EMITTER VOLTAGE

Figure 2. Safe operating area
 ($D = 0$, $T_C = 25^\circ\text{C}$, $T_j \leq 175^\circ\text{C}$;
 $V_{GE} = 0/15\text{V}$)



T_C , CASE TEMPERATURE

Figure 3. Power dissipation as a function of case temperature
 ($T_j \leq 175^\circ\text{C}$)



T_C , CASE TEMPERATURE

Figure 4. Collector current as a function of case temperature
 ($V_{GE} \geq 15\text{V}$, $T_j \leq 175^\circ\text{C}$)